

FEATURES

- 25 m Ω High-Side MOSFET
- 4.5A continuous current capability in EMSOP8
- 1.0~4.50 A (typ.) Adjustable Current Limit
- Low Current under OUT shorted GND
- Support single layer PCB layout
- Built-in Soft-Start
- $4.5 \sim 6.5 V$ Single Supply Operation
- Available EMSOP8 package.

APPLICATIONS

- USB Charger
- USB Ports/Hubs
- Set-Top Boxes

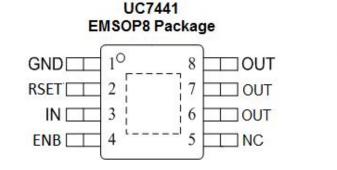
DESCRIPTION

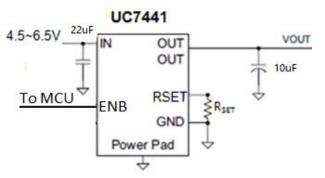
UC7441 is a $25m\Omega$ adjustable current limited power switch intended for applications where heavy capacitive loads and short-circuits are likely to be encountered. These devices offer a programmable current-limit threshold between 1.0A and 4.5 A (typ) via an external resistor. The power-switch rise and fall times are controlled to minimize current surges during turn on/off. UC7441 will enter hiccup mode when OUT voltage is less than 2.85V or OTSD. It can significant reduce the output

UC7441 devices limit the output current to a safelevel by switching into a constant-current mode when the output load exceeds the current-limit threshold.

current and reduce thermal effect to the system.

PACKAGE AND APPLICATION



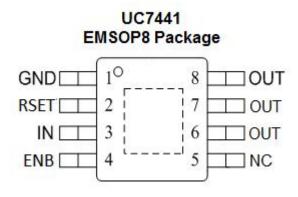


ORDING INFORMATION

Part Number	Package Type	Package Qty	Op Temp(°C)	Mark
UC7441	EMSOP8	3000	-40~85	UC7441



PINOUT



PIN FUNCTIONS

NO.	NAME	TYPE ⁽¹⁾	DESCRIPTION
1	GND	G	Ground connection
2	RSET	Ι	External resistor used to set current-limit threshold;
3	IN	P/I	Power supply/Input voltage connected to Power Switch; connect a 1 μF or greater ceramic capacitor from IN to GND as close to the IC as possible
4	ENB	Ι	Enable input, logic low turns on UC7441, floating forbidden.
5	NC	NC	No Connected;
6,7,8	OUT	О	Power-switch output, connected to VBUS of USB; connect a 22µF or greater ceramic capacitor from OUT to GND as close to the IC as possible; These pins need to be shorted on PCB board;

(1) G = Ground, I = Input, O = Output, P = Power



ABSOLUTE MAXIMUM RATINGS (1)

Over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		MIN	MAX	UNIT
Supply Voltage Range	IN, OUT, RSET, ENB	-0.3	7.0	V
ESD rating, Human Body Model (HBM)	IN, OUT, RSET, ENB		2	kV
Operating Junction Temperature	Tı	-40	125	
Storage Temperature Range	T _{stg}	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

THERMAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	THERMAL METRIC		UNIT
θ_{JA}	EMSOP8 Package thermal impedance ⁽¹⁾	65	°C/W

(1) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

	PARAMETER	MIN	MAX	UNIT
V _{IN}	Input voltage of IN	4.5	6.5	V
V _{OUT}	Output voltage of OUT	4.5	6.5	v
R _{SET}	Resistance of R _{SET}	18	100	kΩ
I _{OUT}	Continuous OUT current	1000	4500	mA
TJ	Operating Junction Temperature	-40	125	°C



ELECTRICAL CHARACTERISTICS

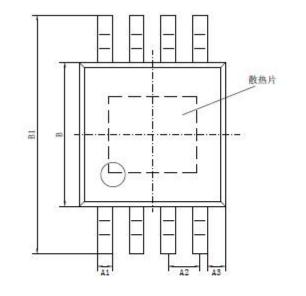
Conditions are: $TA = 25^{\circ}C$, VIN = 5.0 V, ENB = GND and $RSET = 33.0 k\Omega$. Positive current are into pins. All voltages are with respect to GND (unless otherwise noted).

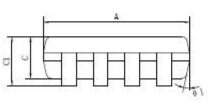
	PARAMETER	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT	
		Power Switch	1	1			
R _{DSON}	EMSOP8 Package	I _{OUT} =1A		25		mΩ	
Tr	OUT voltage rise time			1.73			
Tf	OUT voltage fall time			0.8		ms	
Ton	OUT voltage turn-on time	$C_L = 1 \ \mu F, R_L = 100 \ \Omega,$		2.48			
Toff	OUT voltage turn-off time			2.98			
		Current Limit					
T		Rset=21.5k	2.42	2.70	3.00	А	
Ios	OUT current limited	Rset=13.5k	3.68	4.1	4.55	A	
		Enable Pin (ENB)					
V_{ENB}	ENB threshold voltage, falling		0.8	1.33	2.3	V	
V_{ENB_HYS}	Hysteresis			150		mV	
R _{PD}	Pull Down Resistor		200	290	380	kΩ	
		Hiccup Mode					
Vout_short	OUT Threshold Voltage to enter Hiccup mode			2.85		V	
T _{ON_HICCUP}	ON Time of Hiccup mode		70	130	190	ms	
T _{OFF_HICCUP}	OFF Time of Hiccup mode		0.7	1.3	1.9	s	
		Thermal Shutdown					
	Temperature Rising Threshold 172						
	Hysteresis			20		°C	
	U	NDERVOLTAGE LOCKOUT					
V _{UVLO}	IN rising UVLO threshold voltage		3.75	3.95	4.15	V	
	Hysteresis			100		mV	
		SUPPLY CURRENT					
I _{IN}	IN supply current	VIN=5.0V, ENB=0V		160	280		
I _{INL}	IN Disable Supply Current	VIN=ENB=5.0V		0	2	μΑ	

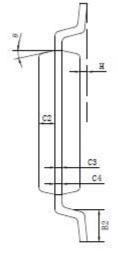


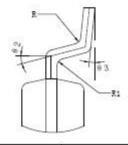
PACKAGE INFORMATION

EMSOP8









尺寸	最小(mm)	最大(mm)	标注	最小(===)	最大(mm)
A	2.90	3.10	CS	0.	152
A1	0.28	0.35	C4	0.15	0.23
A2	0.6	STYP	H	0.02 0.15	
A3	0.3	0.375TYP		12" TYP4	
В	2.90	3.10	01	12" TYP4	
B1	4.70	5.10	0 2	14° IYP	
B2	0.45	0.75	03	0° ~ 6°	
C	0.75	0.95	R	0.15TYP	
C1	2228	1.10	R1	0.15TYP	
C2	0. 328TYP			1993	60 X 662 8